

FEATURES

- No opto feedback
- Patents Pending
- Optimised bipolar output voltages for IGBT/ SiC & Mosfet gate drives
- Configurable dual outputs for all gate drive applications: +15V/-5V, +15V/-10V & +20V/-5V outputs
- Reinforced insulation to UL60950 recognised
- ANSI/AAMI ES60601-1 1MOPP/2MOOPs recognised
- Characterised dv/dt immunity 80kV/μs at 1.6kV
- Characterised partial discharge performance
- 5.2kVDC isolation test voltage 'Hi Pot Test'
- Ultra low coupling capacitance 15pF
- DC link voltage 3kVDC
- 5V, 12V & 24V input voltages
- 105°C operating temperature

PRODUCT OVERVIEW

Offering configurable dual output voltages of +15V/-10V, +20V/-5V and +15V/-5V, the MGJ3 series of DC-DC converters is ideal for powering 'high side' and 'low side' gate drive circuits for IGBTs, Silicon and Silicon Carbide Mosfets in bridge circuits. A choice of asymmetric output voltages allows optimum drive levels for best system efficiency and EMI. The MGJ3 series is characterised for high isolation and dv/dt requirements commonly seen in bridge circuits used in motor drives and inverters. A disable/frequency synchronisation pin simplifies EMC filter design. The MGJ3 protection features include short circuit protection and overload protection.



For full details go to www.murata-ps.com/rohs



SELECTION GUIDE

Order Code ¹	Input Voltage Range	Typical Application	Output 1			Output 2		
			Rated Output Voltage	Rated Output Current	Output Power	Rated Output Voltage	Rated Output Current	Output Power
			V	mA	W	V	mA	W
MGJ3T05150505MC	4.5 - 9	IGBT	+15	120	1.8	-10	120	1.2
MGJ3T12150505MC	9 - 18	IGBT	+15	120	1.8	-10	120	1.2
MGJ3T24150505MC	18 - 36	IGBT	+15	120	1.8	-10	120	1.2
MGJ3T05150505MC	4.5 - 9	SiC	+20	120	2.4	-5	120	0.6
MGJ3T12150505MC	9 - 18	SiC	+20	120	2.4	-5	120	0.6
MGJ3T24150505MC	18 - 36	SiC	+20	120	2.4	-5	120	0.6
MGJ3T05150505MC	4.5 - 9	MOSFET	+15	150	2.25	-5	150	0.75
MGJ3T12150505MC	9 - 18	MOSFET	+15	150	2.25	-5	150	0.75
MGJ3T24150505MC	18 - 36	MOSFET	+15	150	2.25	-5	150	0.75

SELECTION GUIDE (Continued)

Order Code ¹	Input Voltage Range	Typical Application	Output 1				Output 2			
			Load Regulation (Typ) ³	Load Regulation (Max) ³	Ripple & Noise (Typ) ²	Ripple & Noise (Max) ²	Load Regulation (Typ) ³	Load Regulation (Max) ³	Ripple & Noise (Typ) ²	Ripple & Noise (Max) ²
			%	%	mVp-p	mVp-p	%	%	mVp-p	mVp-p
MGJ3T05150505MC	4.5 - 9	IGBT	3	10	69	200	3	10	98	150
MGJ3T12150505MC	9 - 18	IGBT	3	10	85	200	3	10	108	150
MGJ3T24150505MC	18 - 36	IGBT	3	10	83	200	3	10	104	150
MGJ3T05150505MC	4.5 - 9	SiC	3	10	118	275	3	10	49	75
MGJ3T12150505MC	9 - 18	SiC	3	10	139	275	3	10	54	75
MGJ3T24150505MC	18 - 36	SiC	3	10	135	275	3	10	52	75
MGJ3T05150505MC	4.5 - 9	MOSFET	3	10	69	200	3	10	49	75
MGJ3T12150505MC	9 - 18	MOSFET	3	10	85	200	3	10	54	75
MGJ3T24150505MC	18 - 36	MOSFET	3	10	83	200	3	10	52	75

1. Components are supplied in tape and reel packaging, please refer to package specification section. Orderable part numbers are MGJ3TXX150505MC-R7 (23 pieces per reel), or MGJ3TXX150505MC-R13 (92 pieces per reel).

2. See ripple & noise test method.

3. Between 75% and 100% rated output current.

All specifications typical at T_a=25°C, nominal input voltage and rated output current unless otherwise specified.

SELECTION GUIDE (Continued)

Order Code	Nominal Input Voltage	Input Current at Rated Load	Efficiency (Min)	Efficiency (Typ)	Isolation Capacitance	MTTF ¹	
						MIL 217	Telecordia
						kHrs	
MGJ3T05150505MC	5	760	75	78.5	15	889	6662
MGJ3T12150505MC	12	310	78	82	15	939	6596
MGJ3T24150505MC	24	155	77	81	15	915	6596

INPUT CHARACTERISTICS

Parameter	Conditions	Min.	Typ.	Max.	Units
Voltage range	5V input types	4.5	5	9	V
	12V input types	9	12	18	
	24V input types	18	24	36	
Under voltage lock out	Turn on threshold MGJ3T05		4.1		V
	Turn off threshold MGJ3T05		3.0		
	Turn on threshold MGJ3T12		8.1		
	Turn off threshold MGJ3T12		7.5		
	Turn on threshold MGJ3T24		16.7		
	Turn off threshold MGJ3T24		16.1		
Input ripple current	5V input types		18		mA p-p
	12V input types		12		
	24V input types		9		

OUTPUT CHARACTERISTICS

Parameter	Conditions	Min.	Typ.	Max.	Units
Minimum load	Below 10% load, 5V and 15V outputs are clamped to 6V and 16V respectively	10			%
Voltage set point accuracy	Nominal output voltages are at 75% loading		±4		%
Line regulation	Low line to high line			2	%
Transient response	Peak deviation (50-100% & 100-50% load swing)		1.2		%V _{out}
	Settling time		0.25		ms

ISOLATION CHARACTERISTICS

Parameter	Conditions	Min.	Typ.	Max.	Units
Isolation test voltage	Flash tested for 1 second	5200			VDC
	Qualification tested for 1 minute	5200			
Resistance	Viso = 1kVDC	100			GΩ
Continuous barrier withstand voltage	Non-safety barrier application			3000	V

GENERAL CHARACTERISTICS

Parameter	Conditions	Min.	Typ.	Max.	Units
Switching frequency			100		kHz

TEMPERATURE CHARACTERISTICS

Parameter	Conditions	Min.	Typ.	Max.	Units
Operation	See derating graphs	-40		105	°C
Storage		-50		125	
Product temperature rise above ambient	100% Load, Nom V _{in} , Still Air		18		

ABSOLUTE MAXIMUM RATINGS

Short-circuit protection	Continuous
Input voltage, MGJ3 5V input types	12V
Input voltage, MGJ3 12V input types	20V
Input voltage, MGJ3 24V input types	40V

1. Calculated using MIL-HDBK-217 FN2 and Telecordia SR-332 calculation model with nominal input voltage at full load.

TECHNICAL NOTES

ISOLATION VOLTAGE

'Hi Pot Test', 'Flash Tested', 'Withstand Voltage', 'Proof Voltage', 'Dielectric Withstand Voltage' & 'Isolation Test Voltage' are all terms that relate to the same thing, a test voltage, applied for a specified time, across a component designed to provide electrical isolation, to verify the integrity of that isolation.

Murata Power Solutions MGJ3 series of DC-DC converters are all 100% production tested at 5.2kVDC for 1 second and qualification tested at 5.2kVDC for 1 minute.

A question commonly asked is, "What is the continuous voltage that can be applied across the part in normal operation?"

When the insulation in the MGJ3 series is not used as a safety barrier, i.e. provides functional isolation only, continuous or switched voltages across the barrier up to 3kV are sustainable. Long term reliability testing at these voltages continues. Peak Inception voltages measured were in excess of 3.5kV when testing for partial discharge in accordance with IEC 60270. Please contact Murata for further information.

The MGJ3 series has been recognised by Underwriters Laboratory to 250 Vrms Reinforced Insulation, please see safety approval section below.

REPEATED HIGH-VOLTAGE ISOLATION TESTING

It is well known that repeated high-voltage isolation testing of a barrier component can actually degrade isolation capability, to a lesser or greater degree depending on materials, construction and environment. We therefore strongly advise against repeated high voltage isolation testing, but if it is absolutely required, that the voltage be reduced by 20% from specified test voltage.

SAFETY APPROVAL

ANSI/AAMI ES60601-1

The MGJ3 series is recognised to ANSI/AAMI ES60601-1 and provides 1 MOPP (Means Of Patient Protection) and 2 MOOP (Means Of Operator Protection) based upon a working voltage of 250 Vrms max, between Primary and Secondary.

UL 60950

The MGJ3 series has been recognised by Underwriters Laboratory (UL) to UL 60950 for reinforced insulation to a working voltage of 250Vrms with a maximum measured product operating temperature of 105°C.

Creepage and clearance 7mm.

FUSING

The MGJ3 Series of converters are not internally fused so to meet the requirements of UL an anti-surge input line fuse should always be used with ratings as defined below.

Input Voltage, 5V 2A

Input Voltage, 12V 1A

Input Voltage, 24V 0.5A

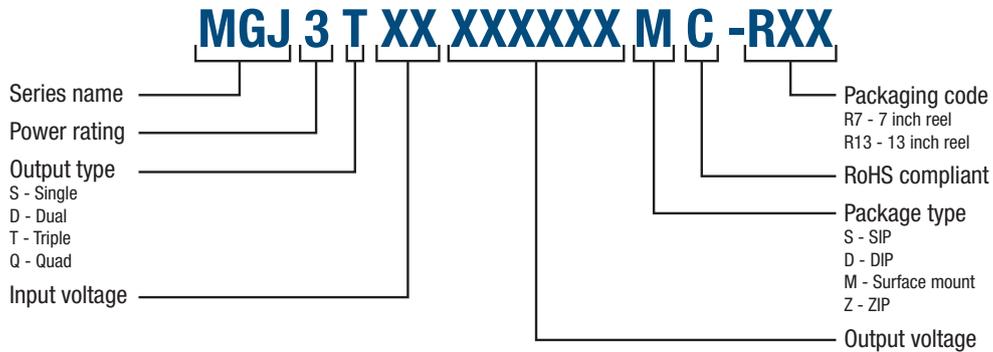
All fuses should be UL recognised, 125V rated.

RoHS COMPLIANCE, MSL AND PSL INFORMATION



This series is compatible with RoHS soldering systems with a peak reflow solder temperature of 245°C and Time Above Liquidus for 90 seconds. as per J-STD-020D.1. The pin termination finish on this product series is Gold with Nickel Pre-plate. The series is backward compatible with Sn/Pb soldering systems. The series has a Moisture Sensitivity Level (MSL) 1. Samples of the product series were tested in accordance with the conditioning described for MSL level 1 in IPS/J-STD-020D.1. The product series passed electrical tests, co-planarity and visual inspection criteria.

PART NUMBER STRUCTURE



CHARACTERISATION TEST METHODS

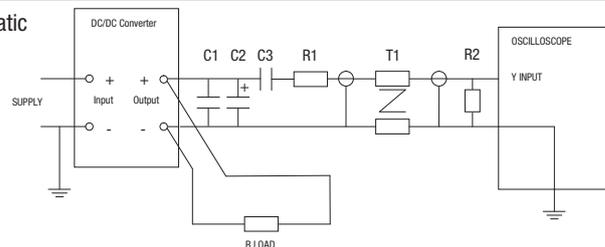
Ripple & Noise Characterisation Method

Ripple and noise measurements are performed with the following test configuration.

C1	1µF X7R multilayer ceramic capacitor, voltage rating to be a minimum of 3 times the output voltage of the DC-DC converter
C2	10µF tantalum capacitor, voltage rating to be a minimum of 1.5 times the output voltage of the DC-DC converter with an ESR of less than 100mΩ at 100 kHz
C3	100nF multilayer ceramic capacitor, general purpose
R1	450Ω resistor, carbon film, ±1% tolerance
R2	50Ω BNC termination
T1	3T of the coax cable through a ferrite toroid
RLOAD	Resistive load to the maximum power rating of the DC-DC converter. Connections should be made via twisted wires

Measured values are multiplied by 10 to obtain the specified values.

Differential Mode Noise Test Schematic



APPLICATION NOTES

Disable/Frequency synchronisation

Please refer to application notes for further information.

		Min	Typ	Max	Units
Disable/Sync ¹	Pull Down Current		0.5		mA
	Input High	2		60	V
	Input Low	-0.6		0.8	V
Synchronisation	Frequency Range	90	100	110	kHz
	Duty Cycle	25		75	%

The $\overline{\text{Dis}}/\text{Sync}$ pin has three modes:

1. When a DC logic low voltage is applied to this pin the MGJ3 is disabled and enters a low quiescent current sleep mode.
2. When this pin is left floating or a DC logic high (CMOS/TTL compatible) voltage is applied the MGJ3 is enabled and operates at the programmed frequency of 100kHz.
3. When a square wave of between 90kHz and 110kHz is applied to this pin, the switcher operates at the same frequency as the square wave. The falling edge of the square wave corresponds to the start of the switching cycle. If the signal is slower than 25Hz, it will be interpreted as enabling and disabling the part. If the MGJ3 is disabled, it must be disabled for 7 clock cycles before being re-enabled.

Note: The $\overline{\text{Dis}}/\text{Sync}$ pin is a high impedance TTL input and can be triggered by noise from external circuits if not treated carefully.

Please refer to "LAYOUT CONSIDERATIONS" and "SYNCHRONISATION CIRCUIT" for further details.

[Click here for general guidance for gate drive applications.](#)

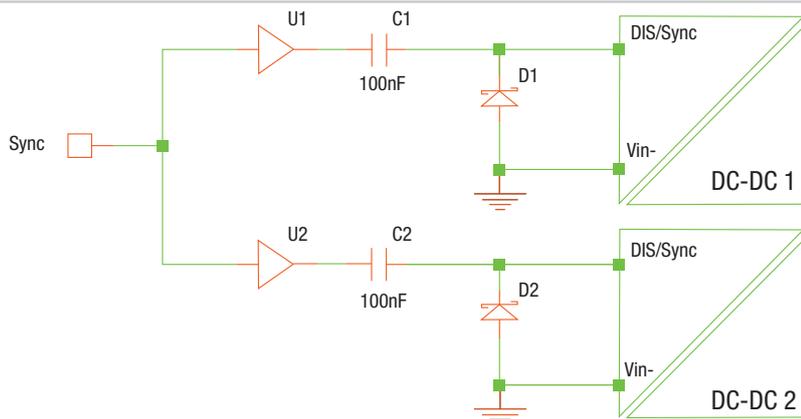
LAYOUT CONSIDERATIONS

Unlike standard isolated DC-DC products the MGJ3 series has been designed specifically for high side gate drive applications where the outputs are being driven to a high voltage at a very high dV/dt. This is possible due to minimum transformer coupling capacitance and considered circuit design regarding common mode transient immunity. It is important that these few simple pcb layout guidelines are implemented so as not to compromise the performance of the DC-DC and that of the overall system.

1. The keep clear area shown must not have any copper traces even on internal layers. This is not only to avoid compromising the creepage and clearance distance but also to minimise capacitive coupling between the noisy output circuits and input control circuits. In general it is good practice to maintain the same band of clearance area running directly through both the DC-DC and the gate drive isolators as shown so that input and output are kept separate and do not overlap or mesh together at any point.
2. A top layer ground plane copper area connected to $-V_{in}$ can be used to create an effective screen to the underside of the MGJ3 series and can also be used as a guard ring for the gate drive isolator inputs. If the $\overline{\text{Dis}}/\text{Sync}$ pin is being used then it is imperative that it follows a route covered by this screen to avoid differential pick up. It should also be kept as short as possible.

Please refer to "PACKAGE SPECIFICATIONS" for recommended layout.

SYNCHRONISATION CIRCUIT



1. A suggested synchronisation circuit is shown. C1 and C2 are 100nF capacitors. D1 and D2 are schottky diodes. The capacitive coupling and close connected diode ensures that a transition from high to low is seen at the input pin even in a noisy environment or when there is a slight ground shift between devices.
2. If the $\overline{\text{Dis}}/\text{Sync}$ pin is not used for synchronisation, then a 22nF capacitor can be added between the $\overline{\text{Dis}}/\text{Sync}$ pin and $-V_{in}$ pin to improve noise immunity. If the functionality of $\overline{\text{Dis}}/\text{Sync}$ is not required, the $\overline{\text{Dis}}/\text{Sync}$ pin can be connected directly to the $+V_{in}$ pin to improve noise immunity.
3. One very effective method to reduce common mode transient interference is to add a common mode filter to the DC input. It may only be necessary to add one before splitting the supply to each DC-DC.

APPLICATION NOTES

Start-up times

Typical start up times for this series, with no additional output capacitance are:

Output capacitance must not exceed:

Part No.	Start-up times
	ms
MGJ3T05150505MC	15
MGJ3T12150505MC	15
MGJ3T24150505MC	15

Output Voltage	Maximum output capacitance
V	µF
15	120
5	220

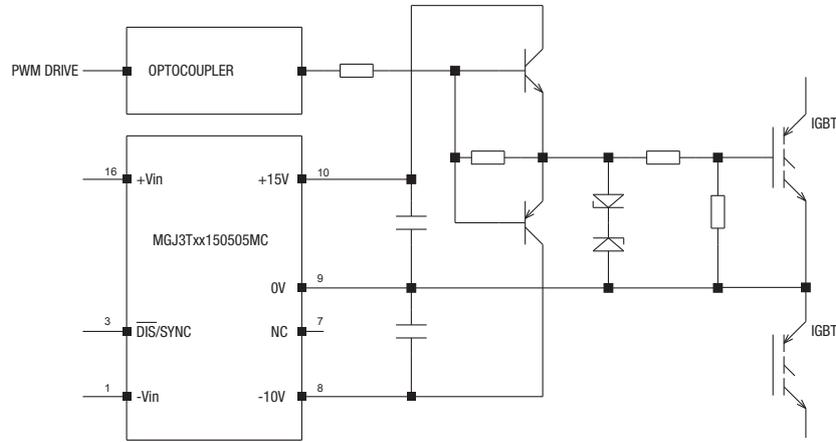
Output configurations for power switches

Terminal	IGBT	SIC	MOSFET
(P10) 15V Output	+15V 0.12A	+20V 0.12A	+15V 0.15A
(P9) 15V Return 5VA Output	0V	No connection	0V
(P7) 5VA Return 5VB Output	No connection	0V	-5V 0.15A
(P8) 5VB Return	-10V 0.12A	-5V 0.12A	No connection

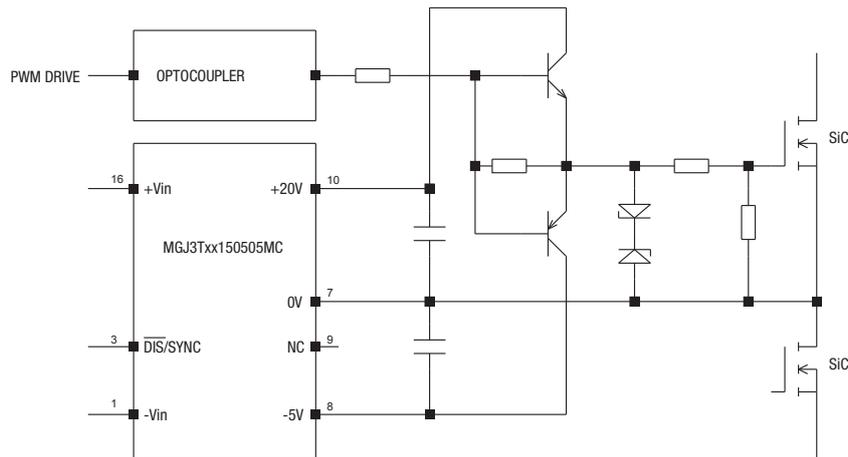
APPLICATION NOTES (Continued)

Schematic for driving IGBT, SiC & MOSFET

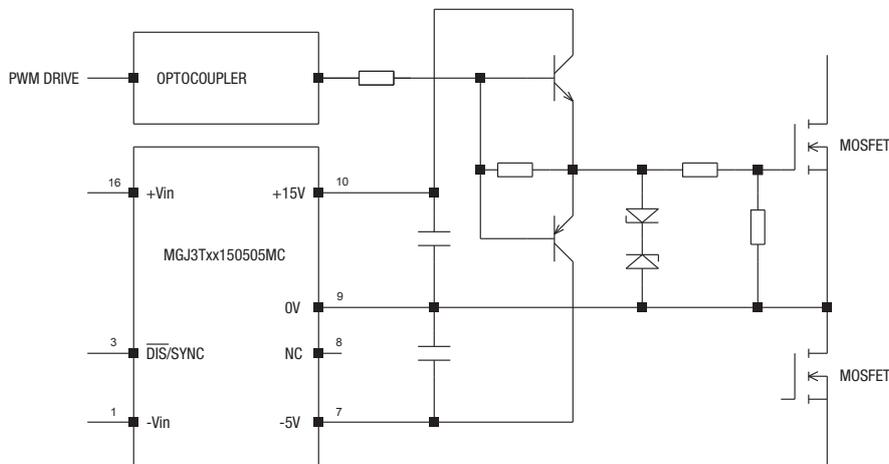
MGJ DC-DC CONNECTIONS FOR DRIVING IGBT DEVICES



MGJ DC-DC CONNECTIONS FOR DRIVING SiC DEVICES

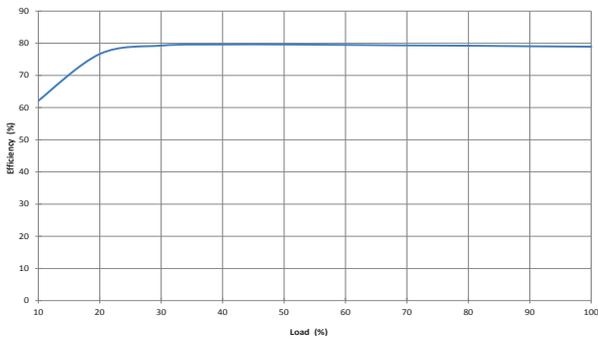


MGJ DC-DC CONNECTIONS FOR DRIVING MOSFET DEVICES

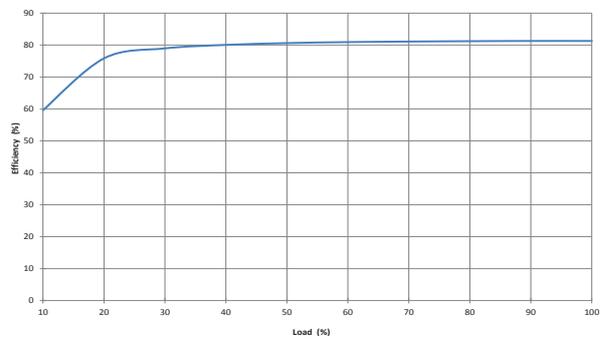


EFFICIENCY VS LOAD

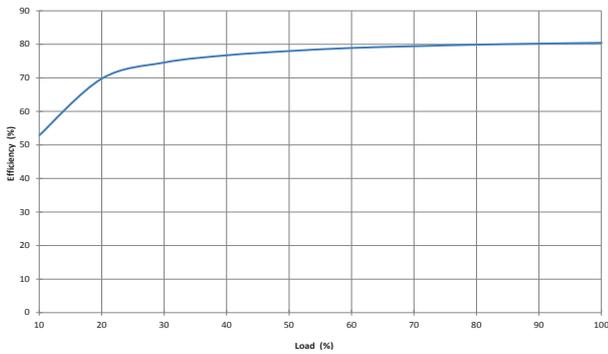
MGJ3T05150505MC



MGJ3T12150505MC

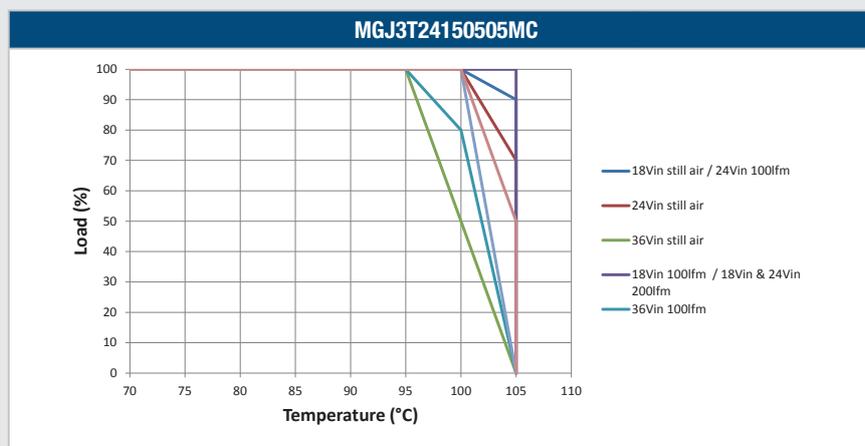
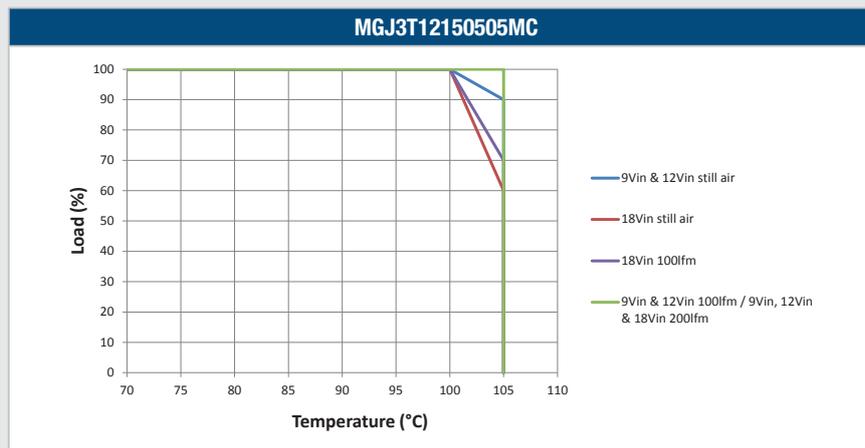
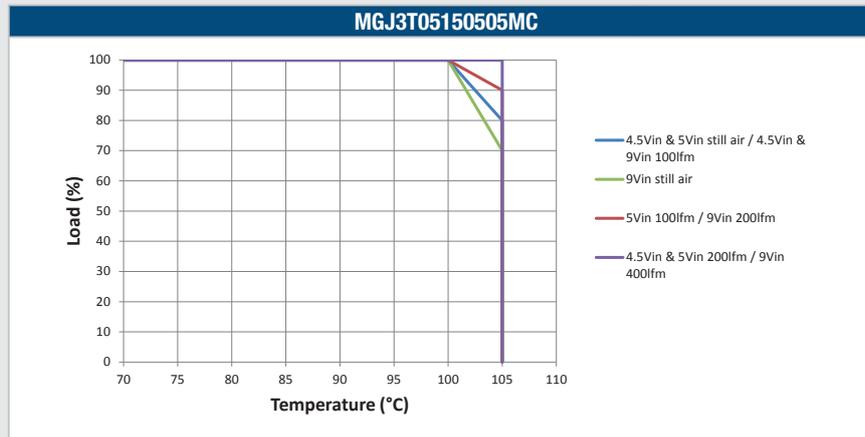


MGJ3T24150505MC



DERATING GRAPHS

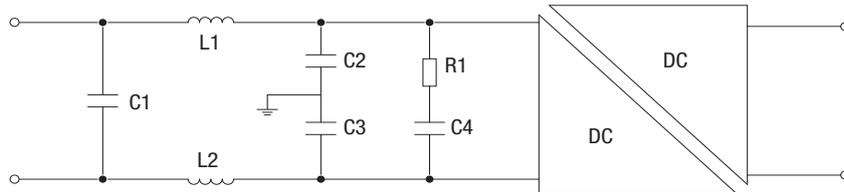
Derating curves are based on IPC-9592. With no derating some components may be operating at the manufacturers maximum temperature ratings.



EMC FILTERING AND SPECTRA

FILTERING

The following filter circuit and filter table shows the input filters typically required to meet EN55022 Quasi-Peak Curve A or B. If a high dv/dt above 80kV/us is expected from output to input it is advised that a common mode filter is used on the input without Y capacitors. This will reduce the common mode current and reduce interference with primary side circuits.



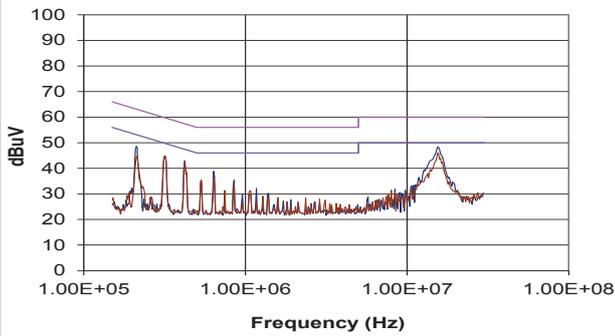
TO MEET CURVE B

Part Number	C1	L1	L2	C2	C3	R1	C4
MGJ3T05150505MC	1.5μF	476R8SC		10nF	10nF	500mΩ	220μF
MGJ3T12150505MC	1.5μF	476R8SC		10nF	10nF	500mΩ	220μF
MGJ3T24150505MC	1.5μF	476R8SC		10nF	10nF	500mΩ	220μF

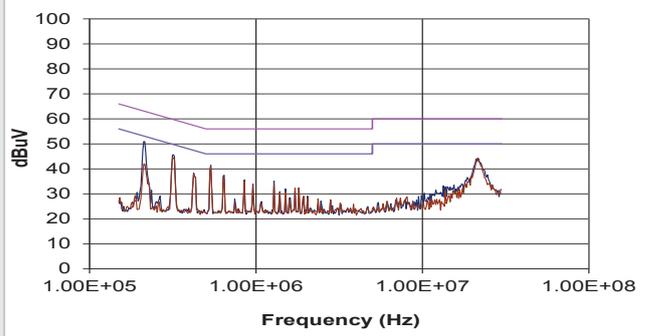
C1, C2 & C3 Polyester or ceramic capacitor

C4 Electrolytic capacitor (note R1 could be omitted if C4 has ESR >= R1)

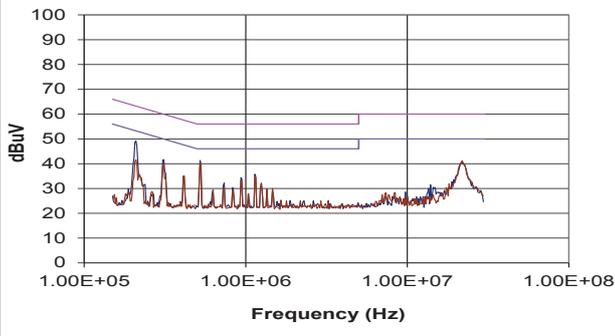
MGJ3T05150505MC



MGJ3T12150505MC

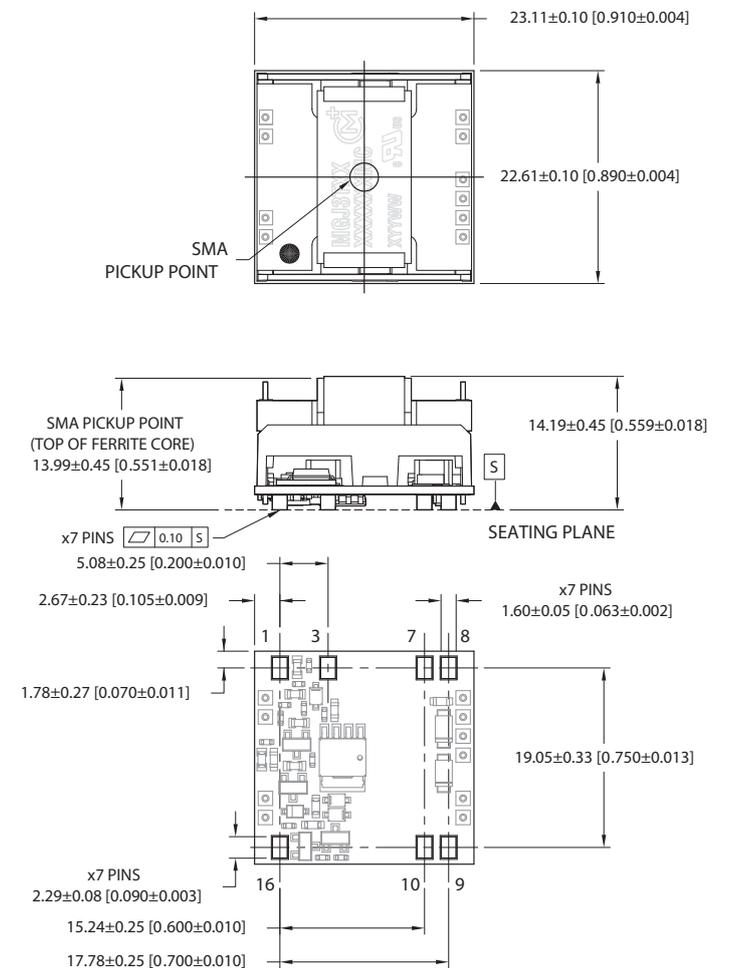


MGJ3T24150505MC



PACKAGE SPECIFICATIONS

MECHANICAL DIMENSIONS



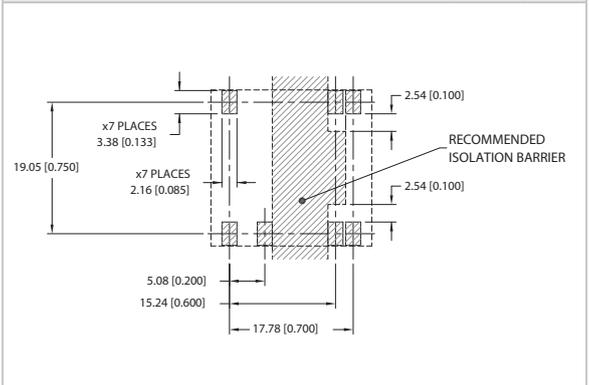
All dimensions in mm (inches). Controlling dimensions in mm.
 Components shown for reference only

Weight: 10.70g

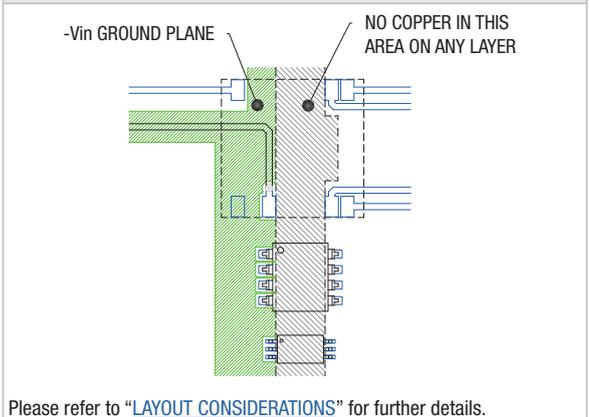
PIN CONNECTIONS

Pin	Function
1	-Vin
3	Dis/Sync
7	5VA RTN
	5VB
8	5VB RTN
	15V RTN
9	5VA
	15 Vout
10	15 Vout
16	+Vin

RECOMMENDED FOOTPRINT DETAILS

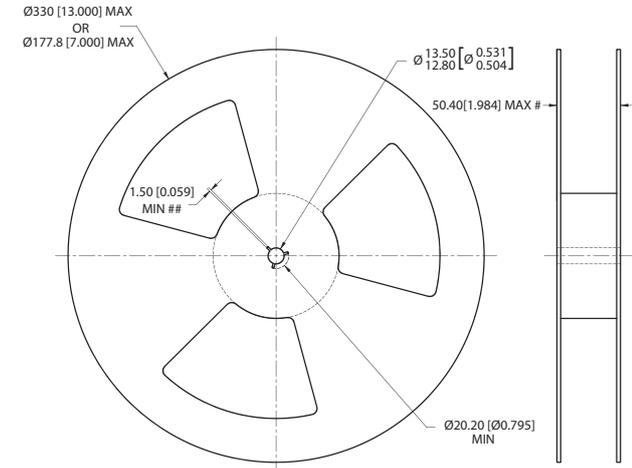


RECOMMENDED LAYOUT



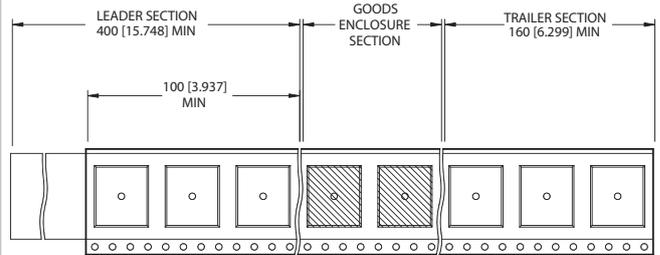
TAPE & REEL SPECIFICATIONS

REEL OUTLINE DIMENSIONS



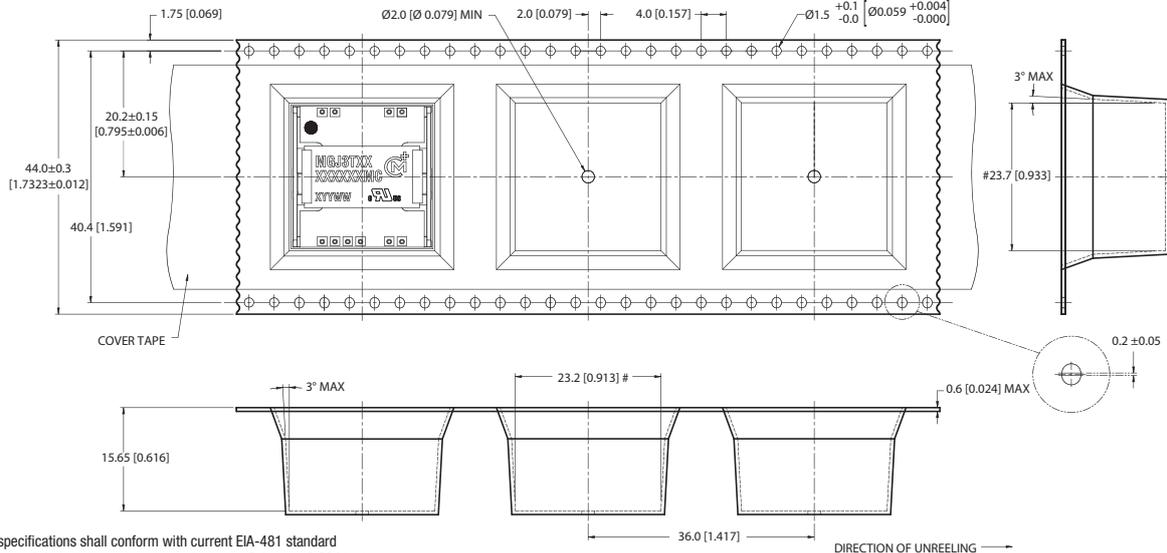
Tape & Reel specifications shall conform with current EIA-481 standard
 Unless otherwise stated all dimensions in mm(inches)
 Controlling dimension is mm
 # Measured at hub
 ## Six equally-spaced slots on 180mm/7" reel

REEL PACKAGING DETAILS



Reel Quantity: 7" - 23 or 13" - 92

TAPE OUTLINE DIMENSIONS



Tape & Reel specifications shall conform with current EIA-481 standard
 Unless otherwise stated all dimensions in mm(inches) ±0.1mm (±0.004 inches)
 Controlling dimension is mm
 Components shall be orientated within the carrier tape as indicated
 # Measured on a plane 0.3mm above the bottom pocket



This product is subject to the following **operating requirements** and the **Life and Safety Critical Application Sales Policy**:
 Refer to: <http://www.murata-ps.com/requirements/>

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